Supporting Information

Tuning the Conduction Band for Interfacial Electron Transfer: Dye-Sensitized Sn_xTi_{1-x}O₂ Photoanodes for Water Splitting

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Supplemental Materials Characterization

As mentioned in the main text, two separate SnO₂ pastes were prepared using small (~5 nm), synthesized¹ particles (SnO₂-S) and larger (~22-43 nm), commercial particles (SnO₂-L). Herein, the notation SnO₂-S and SnO₂-L for "Small" and "Large," respectively, will be used to differentiate these two samples. Notably, there were no differences in IET behavior (Figure S10 and Table S1) or parameters extracted from PXRD measurements (Table S11 and Table S12). SnO₂-L was chosen for NIR spectroelectrochemistry and Tauc measurements because the film was thicker and more uniform than SnO₂-S (see Table S5), which resulted in higher, more reliable signal in NIR spectroelectrochemistry and Tauc measurements.



Near-Infrared (NIR) Spectroelectrochemistry and Tauc Measurements

Figure S1. Normalized NIR spectroelectrochemistry measurements of **RuP**-sensitized Sn_xTi_{1-x}O₂ in 0.1 M HClO₄ to determine the conduction band minimum (E_{CBM}) of Sn_xTi_{1-x}O₂, showing E_{CBM} shift to more oxidizing potentials as the Sn content increases. Data points (black circles) represent the change in absorbance at 800 nm relative to the most positive applied potential (E_a) and were fit to Equation 4 in the main text. The data plotted above were normalized on the amplitude extracted from the fit in Equation 4 (see ΔA_0 in Table S2).



Figure S2. Raw NIR spectroelectrochemistry measurements of $Sn_xTi_{1-x}O_2$ showing all of the data points collected without normalization. Data points (black circles) are the change in absorbance at 800 nm relative to the most positive applied potential (*E_a*) and were fit to Equation 4 in the main text (red line).



Figure S3. Optical absorption spectra of **RuP**-sensitized $Sn_xTi_{1-x}O_2$ in 0.1 M HClO₄ (pH 1) collected for NIR spectroelectrochemical measurements. Spectra are plotted as difference spectra relative to the most positive potential in each dataset. Potential ranges are reported on the right side of each plot as they were measured in V vs. Ag/AgCl (can be converted to NHE by adding 0.197 V).² The potential steps between each spectra in each series was 0.1 V. Spectra plotted as dashed lines were excluded from the fit to determine *E*_{CBM} shown in Figure S1-2 due to deviations from exponential behavior (which only holds close to the band edge) or sample degradation (e.g., burning at high reducing potentials). A gray dashed line is included at 800 nm, where data points were taken to determine *E*_{CBM}.



Figure S4. Tauc plots and linear fits to extract the bandgap (E_G) of Sn_xTi_{1-x}O₂ measured using a Shimadzu UV-2600 with an ISR-2600Plus integrating sphere accessory as described in the main text. The extracted bandgaps are tabulated in Table S3 below.



282

0.5

0.45

292

290 288 286 284 282

Binding Energy (eV)

530

Binding Energy (eV)

528

X-Ray Photoelectron Spectroscopy Measurements

0.

0.4

466 464 462 460 458 456

Binding Energy (eV)

Figure S5. High-resolution XPS measurements of Sn_xTi_{1-x}O₂ in the Ti 2p, Sn 3d, O 1s, and C 1s regions. Spectra were charged corrected to the main adventitious carbon peak in the C 1s region, assuming a binding energy of 284.8 eV.³ Data were fit in CasaXPS using the GL(30) peak function and the resulting fits are shown in Tables S13-S16.

2

534 532

0

500

495 490 485 480

Binding Energy (eV)



Figure S6. Relative composition for Sn_{0.25}Ti_{0.75}O₂ (Sn₂₅), Sn_{0.5}Ti_{0.5}O₂ (Sn₅₀), and Sn_{0.75}Ti_{0.25}O₂ (Sn₇₅) as determined by XPS vs. the stoichiometric ratio used in the synthesis. The compositions were calculated using relative sensitivity factor (RSF) values calculated relative to the oxide and hydroxide peaks in the O 1s region for the pure metal oxides (TiO₂ and SnO₂) assuming a 1:2 stoichiometric ratio of metal to oxide. Using both commercial and synthesized samples, RSF values of 2.3 ± 0.1 and 12.8 ± 0.3 were determined for Ti and Sn, respectively. Errors represent the standard deviation of the average of multiple samples.

Transmission Electron Microscopy



Figure S7. TEM micrograph of Sn_{0.5}Ti_{0.5}O₂, showing that particles are ca. 5 nm in size, consistent with PXRD, and appear to have a growth pattern consistent with the rutile Wulff construction (see inset, adapted and redrawn from Ref. 4).

Powder X-Ray Diffraction Measurements



Figure S8. PXRD patterns of $Sn_xTi_{1-x}O_2$ fit to a sum of Lorentzian functions. The resulting fit parameters are shown in Tables S6-S12.





Figure S9. Representative spectra of dry **RuP**-sensitized $Sn_xTi_{1-x}O_2$ fit to a sum of Gaussians to compare the relative multiplicity fraction as a function of composition (see Figure 4 and Table S18). Spectra were also used to determine dye loadings as shown below in Table S5.



Figure S10. Fits of pre-edge X-ray absorption spectra at the Ti K-edge of $Sn_xTi_{1-x}O_2$. Data were fit using the Athena XAS data processing software, part of the Demeter package.⁵ Fit parameters are shown in Table S17.

Periodic Density Functional Theory Calculations



Figure S11. Conduction band density of states (DOS) for $Sn_xTi_{1-x}O_2$ calculated using periodic DFT, with rutile TiO₂ (r-TiO₂) included instead of anatase TiO₂ (a-TiO₂). Partial DOS for Ti, Sn, and O are shown in blue, orange, and green solid lines, respectively. The total DOS is shown as a dashed black line. Excited states potentials of **RuP** are included for reference.



Figure S12. Integrated density of states (DOS) near the band edge calculated using periodic DFT. The data are shown in solid-colored lines and the fits to Equation 4 in the main text are shown in dashed black lines. The fit results are shown in Table S4 and were used to correct E_{CBM} values to match the experimental values in Figure 5a in the main text and Figure S7 above.

Ultrafast Transient Absorption Spectroscopy



Figure S13. RuP-sensitized ZrO₂ fs-TAS measurements to determine the **RuP**²⁺ ground-excited state isosbestic point (occurs at 402 nm, denoted by a gray dashed line). Samples were photoexcited at 515 nm and probed using a white light continuum generated in CaF₂. The dye loading on ZrO₂ was $(3.1 \pm 0.4) \times 10^{-8}$ mol cm⁻² as determined by UV-Vis spectroscopy as previously described.^{6,7}



Figure S14. Comparison of representation fs-TAS traces for small, synthesized (SnO₂-S) and larger, commercial (SnO₂-L) **RuP**-sensitized SnO₂ dynamics measured by fs-TAS, illustrating similarity of IET character shown to be within error in Table S1.

Materials Characterization Data Tables

Table S1. Fit parameters	obtained from fs-TA	AS measurements.	Errors ar	e reported as	the standard
deviation of the average	of four independently	y measured sample	es, excep	ot where othe	rwise noted.

	A_{l}	A_3	$ au_3$ (ps)	ß	$\langle \tau_3 \rangle^{\rm b}$ (ps)	Scaling (mOD)
a-TiO ₂	0.2 ± 0.1	0.8 ± 0.1	8 ± 2	0.5 ± 0.1	17 ± 10	8 ± 3
Sn0.25Ti0.75O2	0.4 ± 0.1	0.6 ± 0.1	4 ± 1	0.76 ± 0.05	5 ± 2	3 ± 2
Sn0.5Ti0.5O2	0.52 ± 0.07	0.48 ± 0.07	5 ± 1	0.7 ± 0.2	6 ± 3	1.7 ± 0.9
Sn0.75Ti0.25O2	0.66 ± 0.02	0.34 ± 0.02	10 ± 2	0.8 ± 0.2	11 ± 3	1.1 ± 0.4
SnO ₂ -S	0.04 ± 0.09	0.96 ± 0.09	6 ± 3	0.6 ± 0.1	9 ± 4	1.8 ± 1.0
SnO ₂ -L	0.03 ± 0.05	0.97 ± 0.05	5 ± 2	0.53 ± 0.09	8 ± 4	3.1 ± 0.8

^b Errors are propagated using the experimental errors in τ_3 and β .

Table S2. Fit parameters from fits in Figure S1 to Equation 4 to determine the conduction band minimum (E_{CBM}) of Sn_xTi_{1-x}O₂ samples. Errors represent the uncertainty in the fit.

Sample	ECBM (V vs. NHE)	ΔA_{θ} (×10 ⁻³ a.u.)	a (unitless)
a-TiO ₂	-0.2029 ± 0.0010	4.84 ± 0.05	0.29 ± 0.05
Sn0.25Ti0.75O2	-0.076 ± 0.003	1.43 ± 0.04	0.2 ± 0.1
Sn0.5Ti0.5O2	0.085 ± 0.001	0.775 ± 0.010	0.24 ± 0.02
Sn0.75Ti0.25O2	0.171 ± 0.002	0.456 ± 0.006	0.211 ± 0.010
SnO ₂ -L	0.392 ± 0.005	0.62 ± 0.02	0.14 ± 0.01

Table S3. Bandgaps (E_G) of Sn_xTi_{1-x}O₂ extracted using Tauc analysis of films measured using an integrating sphere and valence band maximum (E_{VBM}) determined by subtracting E_G from E_{CBM} . Indirect allowed bandgaps were assumed, unless other noted. Errors represent uncertainty determined by propagation of error.

Sample	E_G (eV)	EVBM (V vs. NHE)
a-TiO ₂	3.26 ± 0.01	3.06 ± 0.01
Sn0.25Ti0.75O2	3.38 ± 0.02	3.30 ± 0.02
Sn0.5Ti0.5O2	3.51 ± 0.01	3.60 ± 0.01
Sn0.75Ti0.25O2	3.364 ± 0.007	3.535 ± 0.008
SnO ₂ -L (direct)	4.03 ± 0.04	4.42 ± 0.04
SnO ₂ -L (indirect)	3.641 ± 0.006	4.033 ± 0.008

Table S4. Fit parameters for the fits in Figure S12 to Equation 4 to determine correction factors to shift the calculated DOS in Figure 5a and Figure S11 to correspond with the experimental E_{CBM} values shown above in Table S2.

Sample	E_{CBM} (eV)	ΔA_{θ} (×10 ⁻³ a.u.)	a (unitless)
a-TiO ₂	3.5260 ± 0.0002	0.0719 ± 0.0005	0.1118 ± 0.0002
r-TiO ₂	3.0631 ± 0.0002	0.0740 ± 0.0004	0.537 ± 0.005
Sn0.25Ti0.75O2	3.1038 ± 0.0006	0.097 ± 0.002	0.176 ± 0.001
Sn0.5Ti0.5O2	3.2148 ± 0.0003	0.0549 ± 0.0006	0.1620 ± 0.0007
Sn0.75Ti0.25O2	3.5105 ± 0.0008	0.094 ± 0.002	0.159 ± 0.002
SnO ₂ -L	2.822 ± 0.002	0.0224 ± 0.0003	0.0525 ± 0.0004

Table S5. Derived parameters from PXRD measurements of $Sn_xTi_{1-x}O_2$. Particle size as a function of composition as determined using the Scherrer equation (Equation 3)⁸ for the three most intense reflections for each polymorph (101, 200, and 105 for anatase and 110, 101, and 211 for rutile, respectively). Lattice constants, *a* and *c*, for rutile polymorph samples were determined from the 110 and 101 peaks, respectively. For a-TiO₂, the 200 and 101 peaks were used to determine *a* and *c*, respectively. Errors represent uncertainty in fit parameters, propagated as appropriate. For both polymorphs, *a* = *b*.

	Particle Size	Lattice	Constants
Sample	d (nm)	a = b (Å)	<i>c</i> (Å)
a-TiO ₂	22 ± 2	3.7833 ± 0.0004	9.52 ± 0.01
r-TiO ₂	12.6 ± 0.4	4.5924 ± 0.0006	2.9586 ± 0.0009
Sn0.25Ti0.75O2	5.3 ± 0.5	4.626 ± 0.002	3.014 ± 0.002
Sn0.5Ti0.5O2	4.4 ± 0.8	4.676 ± 0.002	3.089 ± 0.002
Sn0.75Ti0.25O2	4.4 ± 0.5	4.691 ± 0.002	3.123 ± 0.002
SnO ₂ -S	7 ± 1	4.735 ± 0.001	3.185 ± 0.001
SnO ₂ -L	15.8 ± 0.2	4.7375 ± 0.0004	3.1856 ± 0.0004

Table S6. Dye loadings and film thicknesses of $Sn_xTi_{1-x}O_2$. Dye loadings were determined by UV-Vis measurements in mol cm⁻² as previously described using a modified version of Beer's Law.^{6,7} Loadings were determined by the absorbance at 454 nm, where **RuP** has a molar absorptivity of ~13,400 M⁻¹ cm⁻¹.⁶ Film thicknesses were measured by mechanical profilometry, which was then used to convert to volumetric dye loadings in mol cm⁻² µm⁻¹.

	Loading (mol cm ⁻²) ^a	Film Thickness (µm) ^a	Loading (mol cm ⁻² µm ⁻¹) ^b
a-TiO ₂	$(5 \pm 1) \times 10^{-8}$	5 ± 1	$(1.1 \pm 0.3) \times 10^{-8}$
Sn0.25Ti0.75O2	$(1.7 \pm 0.5) \times 10^{-8}$	0.9 ± 0.4	$(1.8 \pm 0.9) imes 10^{-8}$
Sn0.5Ti0.5O2	$(1.3 \pm 0.6) \times 10^{-8}$	1.1 ± 0.3	$(1.2 \pm 0.7) \times 10^{-8}$
Sn0.75Ti0.25O2	$(1.3 \pm 0.2) \times 10^{-8}$	0.9 ± 0.2	$(1.5 \pm 0.5) \times 10^{-8}$
SnO ₂ -S	$(1.0 \pm 1.0) \times 10^{-8}$	0.8 ± 1.6	$(1 \pm 3) \times 10^{-8}$
SnO ₂ -L	$(1.9 \pm 0.6) \times 10^{-8}$	4 ± 1	$(0.5 \pm 0.2) imes 10^{-8}$

^a Errors are the standard deviation of the mean.

^b Errors are propagated from the standard deviations of the loadings and the film thicknesses.

Table S7. Powder X-ray diffraction fitting summary for anatase TiO₂. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
101	25.312 ± 0.002	2630 ± 30	0.341 ± 0.005
112	36.94 ± 0.04	350 ± 60	0.7 ± 0.1
112	37.840 ± 0.007	780 ± 50	0.35 ± 0.03
112	38.62 ± 0.03	340 ± 50	0.54 ± 0.10
200	48.058 ± 0.005	1400 ± 30	0.42 ± 0.01
105	53.961 ± 0.007	960 ± 40	0.41 ± 0.02
211	55.101 ± 0.008	990 ± 40	0.47 ± 0.02
204	62.742 ± 0.010	840 ± 40	0.48 ± 0.03

Table S8. Powder X-ray diffraction fitting summary for rutile TiO₂. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	27.444 ± 0.003	3770 ± 40	0.674 ± 0.010
101	36.083 ± 0.007	1620 ± 40	$0.64\pm\ 0.02$
200	39.19 ± 0.05	730 ± 60	1.3 ± 0.1
111	41.28 ± 0.01	1040 ± 40	0.62 ± 0.03
210	43.96 ± 0.04	800 ± 50	1.2 ± 0.1
211	54.356 ± 0.005	2870 ± 40	0.71 ± 0.01
220	56.62 ± 0.01	990 ± 40	0.64 ± 0.04
002	62.80 ± 0.03	300 ± 70	0.6 ± 0.1
310	64.15 ± 0.04	1400 ± 100	1.48962 0.2

Table S9. Powder X-ray diffraction fitting summary for $Sn_{0.25}Ti_{0.75}O_2$. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	27.24 ± 0.01	4720 ± 70	1.53 ± 0.03
101	35.52 ± 0.02	2740 ± 70	1.45 ± 0.05
200	38.9 ± 0.1	400 ± 100	1.2 ± 0.4
111	40.85 ± 0.07	1200 ± 100	1.8 ± 0.2
211	53.82 ± 0.01	5800 ± 100	1.88 ± 0.05
220	55.94 ± 0.05	800 ± 100	1.2 ± 0.2
310	63.67 ± 0.07	1500 ± 100	2.3 ± 0.2

Table S10.	Powder X	K-ray c	liffraction	fitting	summary	for	Sn0.5Ti0.5O2.	Errors	are the	uncertain	nty
in the fit.											

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	26.94 ± 0.01	7010 ± 90	1.80 ± 0.03
101	34.78 ± 0.02	4600 ± 100	1.62 ± 0.05
200	39.10 ± 0.09	1600 ± 100	2.6 ± 0.3
211	52.96 ± 0.02	9500 ± 300	2.49 ± 0.06
220	55.18 ± 0.08	1200 ± 200	1.7 ± 0.3
310	62.91 ± 0.10	300 ± 70	0.9 ± 0.3

Table S11. Powder X-ray diffraction fitting summary for Sn_{0.75}Ti_{0.25}O₂. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	26.86 ± 0.01	7270 ± 90	1.86 ± 0.03
101	34.47 ± 0.01	5300 ± 100	1.69 ± 0.04
200	38.66 ± 0.06	1500 ± 100	2.0 ± 0.2
211	52.63 ± 0.02	8500 ± 200	2.26 ± 0.05
220	55.03 ± 0.08	1100 ± 200	1.7 ± 0.3
310	63.2 ± 0.1	1100 ± 100	2.3 ± 0.4

Table S12. Powder X-ray diffraction fitting summary for SnO₂-S. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	26.602 ± 0.007	6030 ± 70	1.22 ± 0.02
101	33.892 ± 0.006	4470 ± 60	0.91 ± 0.02
200	38.07 ± 0.03	2360 ± 90	1.69 ± 0.09
211	51.815 ± 0.008	6510 ± 90	1.35 ± 0.02
220	54.80 ± 0.03	1660 ± 90	1.34 ± 0.10
002	57.97 ± 0.05	450 ± 60	0.8 ± 0.1
310	61.87 ± 0.04	1020 ± 80	1.1 ± 0.1
112	64.78 ± 0.04	760 ± 90	0.7 ± 0.1

Table S13. Powder X-ray diffraction fitting summary for SnO₂-L. Errors are the uncertainty in the fit.

Peak Assignment	Location (deg.)	Area	FWHM (deg.)
110	26.587 ± 0.002	4990 ± 40	0.516 ± 0.006
101	33.881 ± 0.002	4830 ± 40	0.518 ± 0.007
200	37.961 ± 0.008	1530 ± 50	0.55 ± 0.03
111	39.02 ± 0.03	240 ± 40	0.35 ± 0.08
211	51.810 ± 0.002	5880 ± 50	0.566 ± 0.006
220	54.768 ± 0.010	1600 ± 50	0.63 ± 0.03
002	57.85 ± 0.03	1070 ± 60	0.93 ± 0.07
310	61.93 ± 0.01	1540 ± 50	0.68 ± 0.03
112	64.77 ± 0.02	1770 ± 90	0.74 ± 0.05

Table S14. Fit parameters from high resolution XPS scans of Ti 2p region. Errors are uncertainty in the fit determined using Monte Carlo error analysis in CasaXPS.

		Ti 2p _{3/2}			Ti 2p1/2	
Sample	Position (eV)	Area ^a	FWHM (eV)	Position (eV)	Area ^a	FWHM (eV)
a-TiO ₂	458.429 ± 0.002	8090 ± 30	0.979 ± 0.004	464.140 ± 0.005	4040 ± 20	1.98 ± 0.01
r-TiO ₂	458.517 ± 0.002	7480 ± 30	0.964 ± 0.004	464.218 ± 0.005	3740 ± 20	1.93 ± 0.01
Sn0.25Ti0.75O2	458.603 ± 0.003	3600 ± 30	1.092 ± 0.008	464.308 ± 0.010	1800 ± 10	2.03 ± 0.02
Sn0.5Ti0.5O2	458.7 ± 0.01	510 ± 20	1.36 ± 0.04	464.44 ± 0.04	253 ± 9	2.24 ± 0.09
Sn0.75Ti0.25O2	458.690 ± 0.010	860 ± 30	1.22 ± 0.03	464.42 ± 0.04	430 ± 10	2.22 ± 0.09
SnO ₂ -S	-	-	-	-	-	-
SnO ₂ -L	-	-	-	-	-	-

^a Areas constrained such that the area under the $2p_{3/2}$ peak is twice the area under the $2p_{1/2}$ peak to account for the relative population difference due to spin-orbit splitting.

Table S15. Fit parameters from high resolution XPS scans of Sn 3d5 region. Errors are uncertainty in the fit determined using Monte Carlo error analysis in CasaXPS.

		Sn 3d _{5/2}			Sn 3d _{3/2}	
Sample	Position (eV)	Area ^a	FWHM (eV)	Position (eV)	Area ^a	FWHM (eV)
a-TiO ₂	-	-	-	-	-	-
r-TiO ₂	-	-	-	-	-	-
Sn0.25Ti0.75O2	486.352 ± 0.002	6630 ± 30	1.208 ± 0.005	494.775 ± 0.003	4420 ± 20	1.179 ± 0.006
Sn0.5Ti0.5O2	486.492 ± 0.004	2640 ± 20	1.351 ± 0.008	494.861 ± 0.006	1760 ± 10	1.326 ± 0.010
Sn0.75Ti0.25O2	486.470 ± 0.001	12640 ± 30	1.240 ± 0.003	494.876 ± 0.002	8430 ± 20	1.202 ± 0.004
SnO ₂ -S	486.5897 ± 0.0008	42420 ± 40	1.402 ± 0.002	494.998 ± 0.001	28280 ± 30	1.363 ± 0.002
SnO ₂ -L	486.4643 ± 0.0008	47450 ± 50	1.357 ± 0.002	494.871 ± 0.001	31630 ± 30	1.319 ± 0.002

^a Areas constrained such that the area under the $3d_{5/2}$ peak is 1.5 times the area under the $3d_{3/2}$ peak to account for the relative population difference due to spin-orbit splitting.

Table S16. Fit parameters from high resolution XPS scans of O 1s region. Errors are uncertainty in the fit determined using Monte Carlo error analysis in CasaXPS.

	O 1s (Metal Oxide, O ²⁻)			O 1s (Hydroxide, HO ⁻)			O 1s (Water, H ₂ O) ^a	
Sample	Position (eV)	Area	FWHM (eV)	Position (eV)	Area	FWHM ^a (eV)	Position (eV)	Area
a-TiO ₂	529.686 ± 0.003	8500 ± 200	1.07 ± 0.01	530.7 ± 0.2	1500 ± 200	2.4 ± 0.2	-	-
r-TiO ₂	529.745 ± 0.003	8290 ± 60	1.051 ± 0.007	531.13 ± 0.05	1080 ± 70	1.56 ± 0.08	533.09 ± 0.03	770 ± 50
Sn0.25Ti0.75O2	529.966 ± 0.008	5280 ± 100	1.15 ± 0.01	531.24 ± 0.09	1100 ± 50	1.51 ± 0.03	532.7 ± 0.02	2980 ± 90
Sn0.5Ti0.5O2	530.29 ± 0.04	1600 ± 200	1.53 ± 0.07	-	-	-	532.41 ± 0.06	3100 ± 300
Sno.75Tio.25O2	530.22 ± 0.03	3100 ± 600	1.21 ± 0.10	530.9 ± 0.1	1100 ± 600	1.53 ± 0.02	532.500 ± 0.007	5710 ± 70
SnO ₂ -S	530.408 ± 0.006	7100 ± 400	1.12 ± 0.02	531.3 ± 0.1	3900 ± 400	2.06 ± 0.10	-	-
SnO ₂ -L	530.329 ± 0.006	8300 ± 400	1.10 ± 0.02	531.2 ± 0.1	4400 ± 500	2.2 ± 0.1	-	-

^a FWHM of hydroxide (HO⁻) and water (H₂O) O 1s peaks were constrained to be equal.

Table S17. Fit parameters from high resolution XPS scans of C 1s region used for charge correction of other spectra. Values reported are after charge correction has been done. Errors are uncertainty in the fit determined using Monte Carlo error analysis in CasaXPS.

	C 1s (Aliphatic, C-C)		C 1s (Hydroxyl/Ether, C-O) ^{a,b}	C 1s (Ketone, C=O) ^{a,b}	C 1s (Ester/Acid, O-C=O) ^{a,b}	
Sample	Position ^a (eV)	Area	FWHM ^b (eV)	Area	Area	Area
a-TiO ₂	284.80 ± 0.02	680 ± 20	1.27 ± 0.04	190 ± 20	40 ± 10	70 ± 20
r-TiO ₂	284.80 ± 0.01	620 ± 20	1.22 ± 0.03	180 ± 10	22 ± 10	80 ± 10
Sn0.25Ti0.75O2	284.80 ± 0.02	480 ± 20	1.30 ± 0.05	160 ± 10	30 ± 10	60 ± 20
Sn0.5Ti0.5O2	284.80 ± 0.03	210 ± 20	1.46 ± 0.10	19 ± 9	6 ± 9	9 ± 9
Sn0.75Ti0.25O2	284.80 ± 0.05	320 ± 30	1.5 ± 0.1	80 ± 20	20 ± 10	50 ± 20
SnO ₂ -S	284.8 ± 0.3	200 ± 100	2.2 ± 0.8	70 ± 30	0 ± 20	70 ± 60
SnO ₂ -L	284.80 ± 0.05	240 ± 30	1.2 ± 0.1	140 ± 20	6 ± 10	30 ± 20

^a Position was charged corrected to the literature value for aliphatic carbons (C-C). Other peak positions for hydroxyl/ether (C-O), ketone (C=O), and ester/acid (O-C=O) were constrained with respect to the aliphatic carbon position (E_{C-C}) such that they were E_{C-C} + 1.5 eV, E_{C-C} + 3 eV, and E_{C-C} + 4 eV, respectively.

^b FWHM values were constrained to be equal across all peaks.

Assignment	Parameter	a-TiO ₂	r-TiO ₂	Sn0.25Ti0.75O2	Sn _{0.5} Ti _{0.5} O ₂	Sn0.75Ti0.25O2
Edge	Center (eV)	4981 ± 1	4981.2 ± 0.4	4980.6 ± 0.4	4980.8 ± 0.8	4980.7 ± 1.0
	Width (eV)	2.2 ± 0.3	2.9 ± 0.7	3.2 ± 0.7	2.3 ± 0.4	2.3 ± 0.4
	Position (eV)	4967.5 ± 0.6	4967 ± 1	4967 ± 1	4967.1 ± 0.9	4967 ± 1
A_1	Area	0.18 ± 0.03	0.18 ± 0.03	0.05 ± 0.01	0.07 ± 0.02	0.07 ± 0.02
	fwhm (eV)	1.6 ± 0.1	1.5 ± 0.3	1.5 ± 0.2	1.6 ± 0.2	1.9 ± 0.3
	Position (eV)	4970.5 ± 0.8	4969.8 ± 0.2	4969.6 ± 0.3	4969.5 ± 0.3	4969.5 ± 0.3
A ₃	Area	0.3 ± 0.1	0.39 ± 0.04	0.39 ± 0.04	0.38 ± 0.04	0.38 ± 0.04
	fwhm (eV)	1.9 ± 0.3	2.21 ± 0.09	2.32 ± 0.10	2.25 ± 0.09	2.04 ± 0.10
	Position (eV)	4973 ± 4	4973 ± 3	4973 ± 6	4973 ± 5	4973 ± 7
В	Area	0.6 ± 0.5	0.6 ± 0.3	0.5 ± 0.7	0.5 ± 0.5	0.5 ± 0.7
	fwhm (eV)	3.4 ± 0.8	3.9 ± 0.3	4.0 ± 0.3	4.1 ± 0.3	4.2 ± 0.4
	Position (eV)	4978 ± 4	4979 ± 1	4978.2 ± 1.0	4978 ± 3	4978 ± 4
С	Area	2 ± 1	2.0 ± 0.6	1 ± 1	2 ± 1	2 ± 1
	fwhm (eV)	4.3 ± 0.2	4.0 ± 0.2	4.2 ± 0.2	4.9 ± 0.1	5.0 ± 0.1
	Position (eV)	4969 ± 1	-	-	-	-
A2	Area	0.11 ± 0.02	-	-	-	-
	fwhm (eV)	1.3 ± 0.2	-	-	-	-

Table S18. Peak fitting results for pre-edge features in Ti K-edge XANES spectra. Because the data used were normalized, the error function used to describe the background was fixed with a magnitude of 0.5 (corresponding to unity value).

Table S19. UV-Vis Fit Parameters. Errors are the standard deviation of at least three independent measurements.

Transition	Parameter	a-TiO ₂	Sn _{0.25} Ti _{0.75} O ₂	Sn _{0.5} Ti _{0.5} O ₂	Sn _{0.75} Ti _{0.25} O ₂	SnO ₂ -S	SnO ₂ -L
	$E_0 (eV)$	2.53 ± 0.03	2.49 ± 0.02	2.46 ± 0.04	2.46 ± 0.04	2.407 ± 0.007	2.43 ± 0.01
$T \leftarrow S$	FWHM ₀ (eV)	0.44 ± 0.04	0.39 ± 0.03	0.35 ± 0.02	0.37 ± 0.04	0.28 ± 0.02	0.23 ± 0.02
	A ₀	0.11 ± 0.02	0.03 ± 0.01	0.016 ± 0.004	0.024 ± 0.004	0.02 ± 0.01	0.019 ± 0.007
	$E_1 (eV)$	2.695 ± 0.004	2.688 ± 0.003	2.685 ± 0.003	2.683 ± 0.006	2.675 ± 0.005	2.687 ± 0.004
$0 \rightarrow 0$	FWHM ₁ (eV) ^a	0.273 ± 0.006	0.276 ± 0.005	0.277 ± 0.004	0.28 ± 0.01	0.288 ± 0.003	2.282 ± 0.005
	A1	0.6 ± 0.1	0.18 ± 0.04	0.11 ± 0.04	0.14 ± 0.03	0.2 ± 0.1	0.24 ± 0.09
	E ₂ (eV)	2.921 ± 0.003	2.916 ± 0.005	2.914 ± 0.005	2.919 ± 0.007	2.916 ± 0.006	2.920 ± 0.002
$1 \leftarrow 0$	FWHM ₂ (eV) ^a	0.273 ± 0.006	0.276 ± 0.005	0.277 ± 0.004	0.28 ± 0.01	0.288 ± 0.003	2.282 ± 0.005
	A_2	0.56 ± 0.08	0.17 ± 0.04	0.10 ± 0.03	0.13 ± 0.02	0.13 ± 0.10	0.20 ± 0.07
	E3 (eV)	3.204 ± 0.006	3.20 ± 0.02	3.21 ± 0.02	3.21 ± 0.03	3.24 ± 0.03	3.27 ± 0.02
$2 \leftarrow 0$	FWHM ₃ (eV) ^a	0.273 ± 0.006	0.276 ± 0.005	0.277 ± 0.004	0.28 ± 0.01	0.288 ± 0.003	2.282 ± 0.005
	A3	0.67 ± 0.05	0.10 ± 0.02	0.06 ± 0.03	0.09 ± 0.02	0.09 ± 0.07	0.15 ± 0.04

^{a 1}MLCT vibronic transitions were constrained to have equal line widths.

Table S20. DFT-optimized coordinates and lattice vectors (Å) of Sn_xTi_{1-x}O₂.

a-TiO₂

Lattice vectors: a = 3.76511874; b = 3.76511874; c = 9.59441947

Atom	x (Å)	y (Å)	z (Å)
0	0.00000000	0.00000000	1.97701192
0	1.88255937	1.88255937	6.77422165
0	0.00000000	1.88255937	4.37561679
0	1.88255937	0.00000000	9.17282652
0	1.88255937	1.88255937	2.82019781
0	0.00000000	0.00000000	7.61740755
О	1.88255937	0.00000000	5.21880268
0	0.00000000	1.88255937	0.42159295
Ti	0.00000000	0.00000000	0.00000000
Ti	1.88255937	1.88255937	4.79720973
Ti	0.00000000	1.88255937	2.39860487
Ti	1.88255937	0.00000000	7.19581460

r-TiO₂

Lattice vectors: a = 4.58231625; b = 4.58231625; c = 5.89541529

Atom	x (Å)	y (Å)	z (Å)
0	1.39810559	1.39810559	0.00000000
0	0.89305253	3.68926372	1.47385382
0	3.18421065	3.18421065	0.00000000
0	3.68926372	0.89305253	1.47385382
0	1.39810559	1.39810559	2.94770764
0	0.89305253	3.68926372	4.42156147
0	3.18421065	3.18421065	2.94770764
0	3.68926372	0.89305253	4.42156147
Ti	0.00000000	0.00000000	0.00000000
Ti	2.29115812	2.29115812	1.47385382
Ti	0.00000000	0.00000000	2.94770764
Ti	2.29115812	2.29115812	4.42156147

Sn_{0.25}Ti_{0.75}O₂

Atom	x (Å)	y (Å)	z (Å)
0	1.41498443	1.41498443	0.00000000
0	0.92430150	3.70375747	1.43490370
0	3.21307454	3.21307454	0.00000000
0	3.70375747	0.92430150	1.43490370
0	1.44769005	1.44769005	3.01332627
0	0.92430150	3.70375747	4.59174883
0	3.18036892	3.18036892	3.01332627
0	3.70375747	0.92430150	4.59174883
Sn	0.00000000	0.00000000	3.01332627
Ti	2.31402948	2.31402948	1.47679023
Ti	0.00000000	0.00000000	0.00000000
Ti	2.31402948	2.31402948	4.54986231

Lattice vectors: a = 4.62679222; b = 4.62679222; c = 6.02665254

Sn_{0.5}Ti_{0.5}O₂

Lattice vectors: a = 4.66285330; b = 4.66285330; c = 6.17400232

Atom	x (Å)	y (Å)	z (Å)
0	1.40320607	1.40320607	6.09631858
0	0.88988867	3.77296463	1.47737780
0	3.25964723	3.25964723	6.09631858
0	3.77296463	0.88988867	1.47737780
0	1.44153798	1.44153798	3.15312395
0	0.92822058	3.73463272	4.70818548
0	3.22131532	3.22131532	3.15312395
О	3.73463272	0.92822058	4.70818548
Sn	0.00000000	0.00000000	3.10636144
Sn	2.33142665	2.33142665	1.52414030
Ti	0.00000000	0.00000000	6.12606114
Ti	2.33142665	2.33142665	4.67844292

$Sn_{0.75}Ti_{0.25}O_2$

Atom	x (Å)	y (Å)	z (Å)
0	1.46053526	1.46053526	6.21291140
0	0.91920095	3.79849073	1.56987465
0	3.25715642	3.25715642	6.21291140
0	3.79849073	0.91920095	1.56987465
0	1.46053526	1.46053526	3.20633649
0	0.96132429	3.75636738	4.70962394
0	3.25715642	3.25715642	3.20633649
0	3.75636738	0.96132429	4.70962394
Sn	0.00000000	0.00000000	3.16666376
Sn	2.35884584	2.35884584	1.56987465
Sn	0.00000000	0.00000000	6.25258413
Ti	2.35884584	2.35884584	4.70962394

Lattice vectors: a = 4.71198203; b = 4.71198203; c = 6.27949859

SnO₂

Lattice vectors: a = 4.75964688; b = 4.75964688; c = 6.38361102

Atom	x (Å)	y (Å)	z (Å)
0	1.45677288	1.45677288	0.00000000
0	0.92305056	3.83659632	1.59590275
О	3.30287400	3.30287400	0.00000000
0	3.83659632	0.92305056	1.59590275
О	1.45677288	1.45677288	3.19180551
0	0.92305056	3.83659632	4.78770826
0	3.30287400	3.30287400	3.19180551
0	3.83659632	0.92305056	4.78770826
Sn	0.00000000	0.00000000	0.00000000
Sn	2.37982344	2.37982344	1.59590275
Sn	0.00000000	0.00000000	3.19180551
Sn	2.37982344	2.37982344	4.78770826

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